

Photo DMOS-FET Relay

Description

The **LT210** is a miniature 1-Form A solid state relay in a 4 pin SOP package that employs optically coupled MOSFET technology to provide 1500V of input to output isolation. The Input of optical coupler been controlled by a highly efficient GaAlAs infrared LED and MOS FETs on the output side.

Features

- SOP package 4 Pin type in miniature design (4.4×4.3×2.0mm / .173×.169×.083inch)
- Low driver power requirements (TTL/CMOS Compatible)
- High reliability
- Arc-Free with no snubbing circuits
- 1500Vrms Input/Output isolation
- Tape & Reel version available

Applications

- Telecommunications (PC, Electronic notepad)
- Measuring and Testing equipment
- Industrial control
- Security equipments
- High speed inspection machine
- Data communication equipments
- Factory automotive equipments

Photo DMOS-FET Relay Specifications

Part Name: LT210

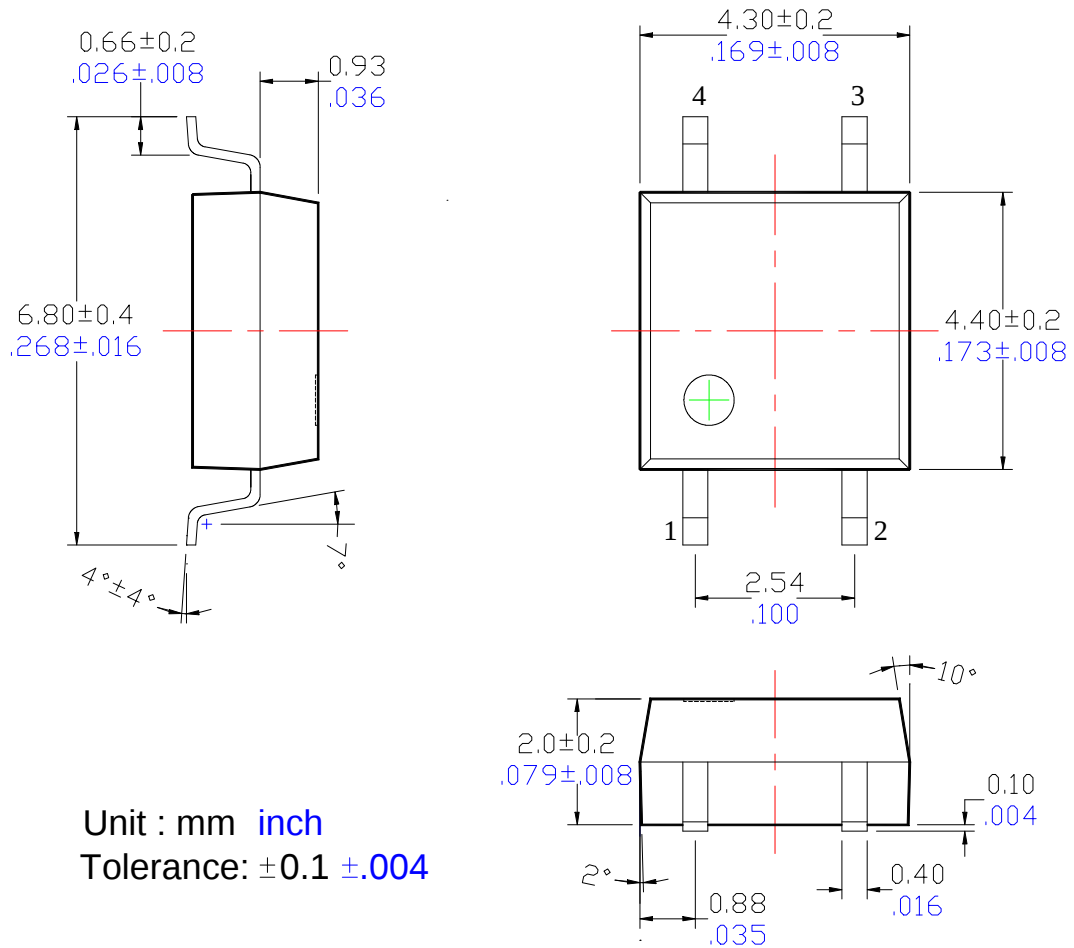
(Load voltage: 400V / Load current: 100mA)

Absolute Maximum Ratings (Ambient Temperature: 25°C)

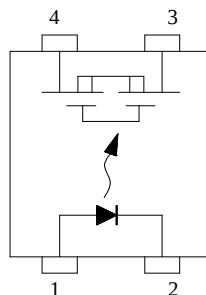
Item		Symbol	Value	Units	Note
Input	Continuous LED Current	I _F	50	mA	
	Peak LED Current	I _{FP}	1000	mA	f=100Hz, duty=1%
	LED Reverse Voltage	V _R	5	V	
	Input Power Dissipation	P _{In}	75	mW	
Output	Load Voltage	V _L	400	V(AC peak or DC)	
	Load Current	I _L	100	mA	
	Peak Load Current	I _{Peak}	0.6	A	100ms(1 pulse)
	Output Power Dissipation	P _{out}	300	mW	
Total Power Dissipation		P _T	350	mW	
I/O Breakdown Voltage		V _{I/O}	1500	V _{rm}	RH=60%, 1min
Operating Temperature		T _{Opr}	-40 to +85	°C	
Storage Temperature		T _{Stg}	-40 to +100	°C	
Pin Soldering Temperature		T _{Sol}	260	°C	10 sec max.

Electrical Specifications (Ambient Temperature: 25°C)

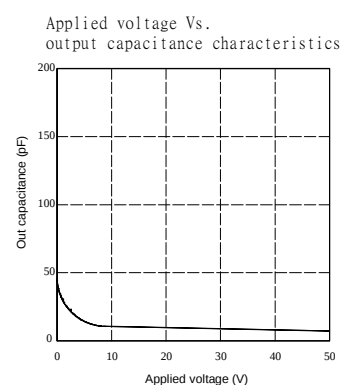
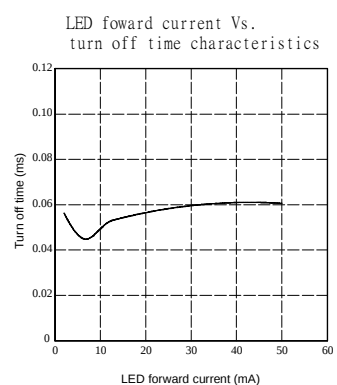
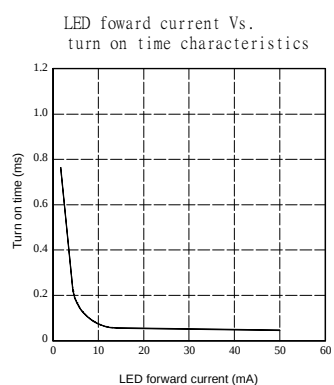
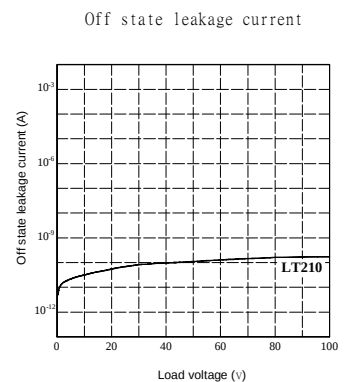
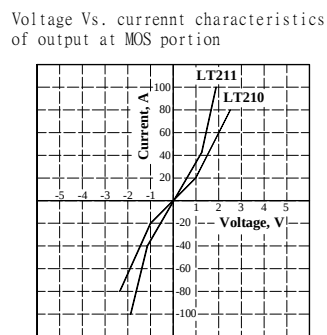
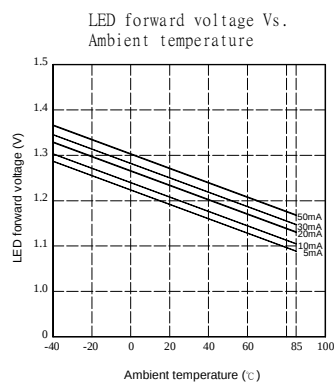
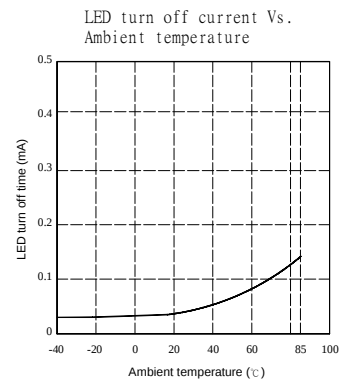
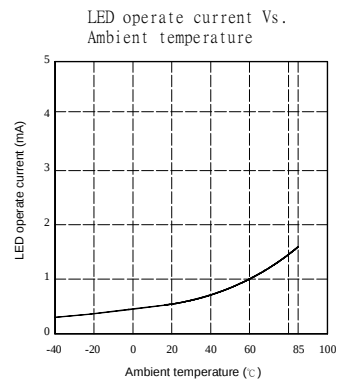
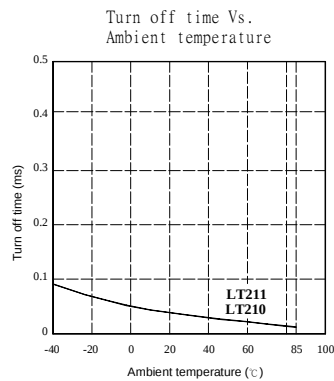
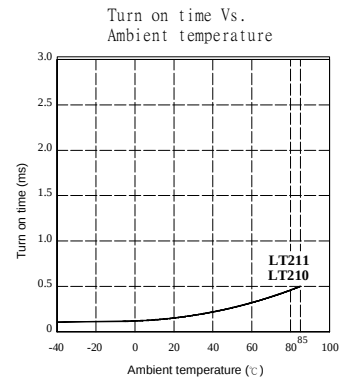
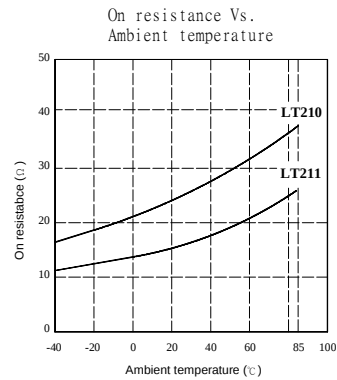
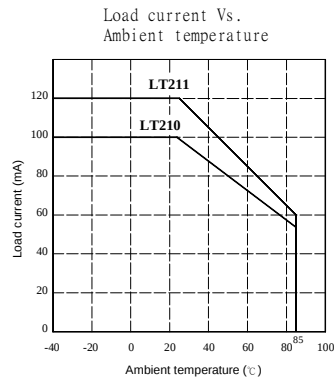
Item		Symbol	MIN.	TYP.	MAX.	Units	Conditions
Input	LED Forward Voltage	V _F		1.2	1.4	V	I _F =10mA
	Operation LED Current	I _{F On}		0.5	3.0	mA	
	Recovery LED Current	I _{F Off}		0.35	0.5	mA	
	Recovery LED Voltage	V _{F Off}	0.5			V	
Output	On-Resistance	R _{On}		20	30	Ω	I _F =5mA, I _L =100mA, Time to flow is within 1 sec.
	Off-State Leakage Current	I _{Leak}			1	μA	V _L =Rating
	Output Capacitance	C _{Out}		110		pF	V _L =0, f=1MHz
Transmis sion	Turn-On Time	T _{On}		0.23	0.5	ms	I _F =5mA, I _L =100mA
	Turn-Off Time	T _{Off}		0.03	0.2	ms	
Coupled	I/O Isolation Resistance	R _{I/O}	10 ⁹			Ω	DC500V
	I/O Capacitance	C _{I/O}		0.8	1.5	pF	f=1MHz

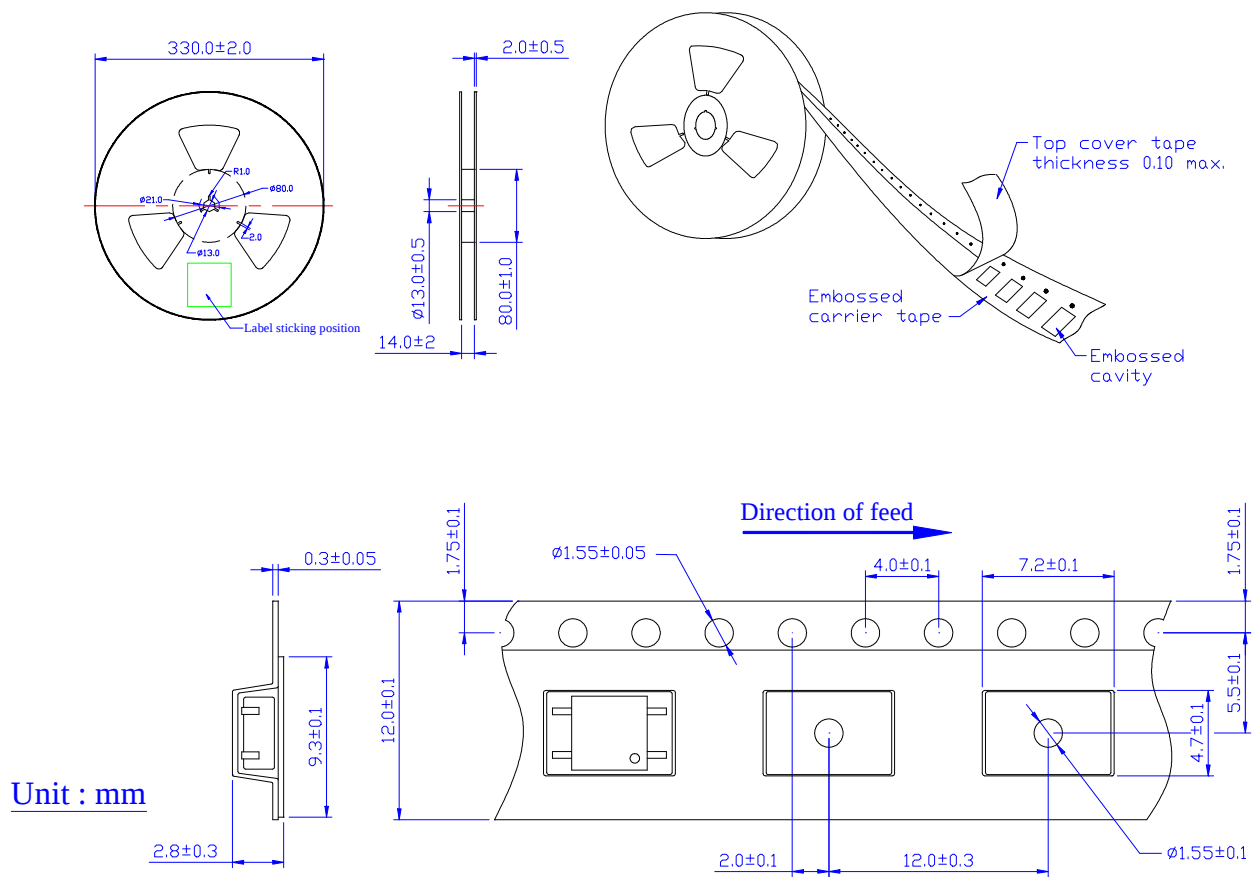


Schematic

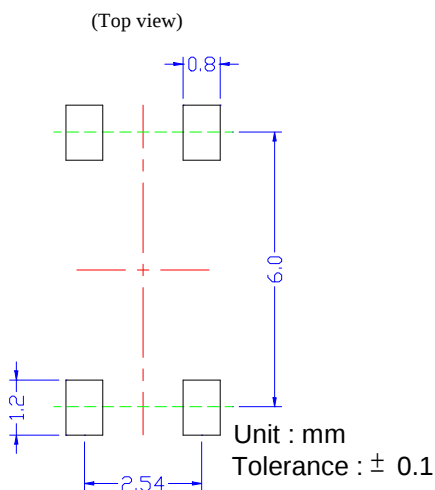


1. LED Anode
2. LED Cathode
3. MOS FET
4. MOS FET



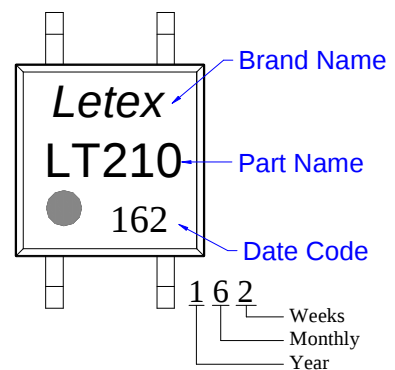


Recommended Mounting Pad



Marking

(Each photo MOS Relay shall be marked with the following information)



- Notes :
1. There shall be 400 mm of leader minimum what may consist of carrier and cover tape follower.
 2. Devices are pockets in accordance with IEC standard IEC286-3 (JIS C 0806) and specifications given above.
 3. Packaging : 2,000pcs per reel, 2 reel per box, 5 boxes per carton.